- **Rugged Triple-Diffused Planar Construction**
- 2.5 A Continuous Collector Current
- **Operating Characteristics Fully Guaranteed** at 100°C
- 850 Volt Blocking Capability
- 50 W at 25°C Case Temperature

# **TO-220 PACKAGE** (TOP VIEW) CC 2 $\mathsf{E} \subseteq$ 3

Pin 2 is in electrical contact with the mounting base.

MDTRACA

# absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Collector-base voltage (I <sub>E</sub> = 0)	V <sub>CBO</sub>	850	V
Collector-emitter voltage (V <sub>BE</sub> = 0)	V <sub>CES</sub>	850	V
Collector-emitter voltage (I <sub>B</sub> = 0)	V <sub>CEO</sub>	400	V
Emitter-base voltage	V <sub>EBO</sub>	10	V
Continuous collector current	I <sub>C</sub>	2.5	Α
Peak collector current (see Note 1)	I <sub>CM</sub>	8	Α
Continuous device dissipation at (or below) 25°C case temperature	P <sub>tot</sub>	50	W
Operating junction temperature range	Ti on	-65 to +150	°C
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C
NOTE 1: This value applies for $t_p \le 10$ ms, duty cycle $\le 2\%$ .			

1: This value applies for  $t_n \le 10$  ms, duty cycle  $\le 2\%$ .

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# TIPL770 NPN SILICON POWER TRANSISTOR

MARCH 1984 - REVISED MARCH 1997

# electrical characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS				MIN	TYP	MAX	UNIT
V <sub>CEO(sus)</sub>	Collector-emitter sustaining voltage	I <sub>C</sub> =	100 mA	L = 25 mH	(see Note 2)	400			V
I <sub>CES</sub>	Collector-emitter cut-off current	V <sub>CE</sub> = V <sub>CE</sub> =		$V_{BE} = 0$ $V_{BE} = 0$	T <sub>C</sub> = 100°C	MILM		5 200	μΑ
I <sub>CEO</sub>	Collector cut-off current	V <sub>CE</sub> =	400 V	I <sub>B</sub> = 0	M.M.M.100X.C	ONLY		5	μΑ
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> =	10 V	I <sub>C</sub> = 0	WWW.100Y.	CONT	N	1	mA
h <sub>FE</sub>	Forward current transfer ratio	V <sub>CE</sub> =	5 V	$I_{\rm C} = 0.5  {\rm A}$	(see Notes 3 and 4)	20		60	
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>B</sub> = I <sub>B</sub> =	0.2 A 0.5 A 0.5 A	$I_{C} = 1 A$ $I_{C} = 2.5 A$ $I_{C} = 2.5 A$	(see Notes 3 and 4) $T_C = 100^{\circ}C$	ON COM	LTW	1.0 2.5 5.0	V
V <sub>BE(sat)</sub>	Base-emitter saturation voltage	I <sub>B</sub> = I <sub>B</sub> =	0.2 A 0.5 A 0.5 A	$I_{C} = 1 A$ $I_{C} = 2.5 A$ $I_{C} = 2.5 A$	(see Notes 3 and 4) $T_C = 100^{\circ}C$	100 X.CO	M.T.MC	1.0 1.2 1.3	V
f <sub>t</sub> .10	Current gain bandwidth product	V <sub>CE</sub> =	10 V	$I_{\rm C} = 0.5  {\rm A}$	f = 1 MHz	N.100.	12	TW	MHz
C <sub>ob</sub>	Output capacitance	V <sub>CB</sub> =	20 V	I <sub>E</sub> = 0	f = 0.1 MHz	W.	55	W	pF

NOTES: 2. Inductive loop switching measurement.

- 3. These parameters must be measured using pulse techniques,  $t_p$  = 300  $\mu$ s, duty cycle  $\leq$  2%.
- 4. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

# thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
R <sub>BJC</sub> Junction to case thermal resistance		1007	2.5	°C/W

# inductive-load-switching characteristics at 25°C case temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS †			MIN	TYP	MAX	UNIT
sv	Voltage storage time	20M.TW	W.100	COM			2	μs
t <sub>rv</sub>	Voltage rise time	$I_C = 2.5 \text{ A}$ $V_{BE(off)} = -5 \text{ V}$	$I_{B(on)} = 0.5 A$ (see Figures	(see Figures 1 and 2)	111	-1	200	ns
t <sub>fi</sub>	Current fall time				1	111111	200	ns
t <sub>ti</sub>	Current tail time					-111	50	ns
хо	Cross over time			100Y.C		444	300	ns
tsv	Voltage storage time	A CON	N WWW	(see Figures 1 and 2)		WW	2.5	μs
trv	Voltage rise time	1 25 AM. 1				-15	400	ns
t <sub>fi</sub>	Current fall time	$I_{C} = 2.5 \text{ A}$ $V_{BE(off)} = -5 \text{ V}$	$I_{B(on)} = 0.5 A$ $T_{C} = 100^{\circ}C$			AA.	250	ns
t <sub>ti</sub>	Current tail time	$V_{BE(off)} = -5 V$	1 <sub>C</sub> = 100°C		N	1/1	50	ns
xo	Cross over time			TW.100 COM.1	-1		500	ns

<sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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# **PRODUCT** INFORMATION WWW.100Y.COM.TV

#### PARAMETER MEASUREMENT INFORMATION

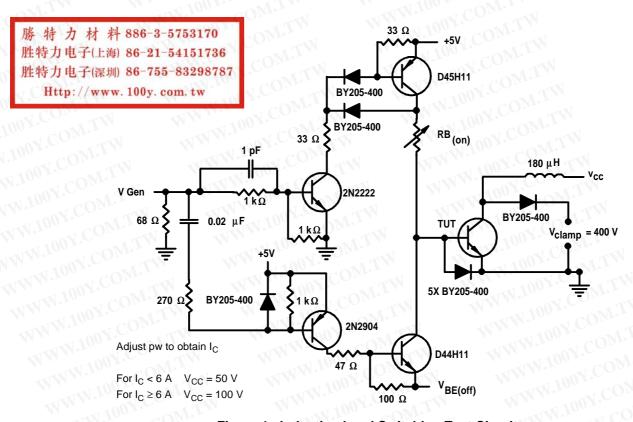
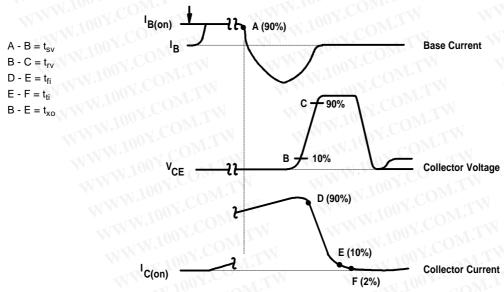


Figure 1. Inductive-Load Switching Test Circuit



NOTES: A. Waveforms are monitored on an oscilloscope with the following characteristics:  $t_r < 15$  ns,  $R_{in} > 10 \Omega$ ,  $C_{in} < 11.5$  pF. B. Resistors must be noninductive types.

Figure 2. Inductive-Load Switching Waveforms



# TYPICAL CHARACTERISTICS

# TYPICAL DC CURRENT GAIN VS COLLECTOR CURRENT TCP770AD TC = 125°C TC = 25°C TC = -65°C TC = -65°C

# **COLLECTOR-EMITTER SATURATION VOLTAGE**

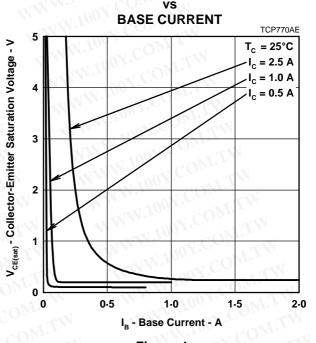
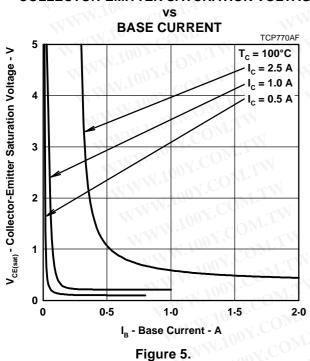
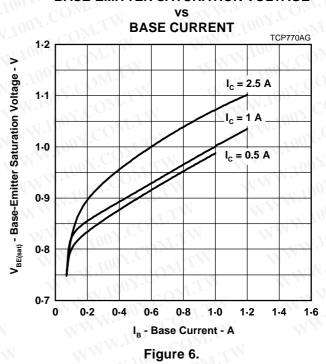


Figure 4.

# **COLLECTOR-EMITTER SATURATION VOLTAGE**



# **BASE-EMITTER SATURATION VOLTAGE**



## PRODUCT INFORMATION

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#### MAXIMUM SAFE OPERATING REGIONS

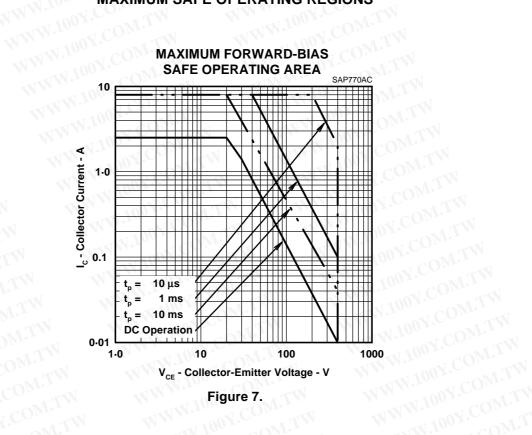


Figure 7.

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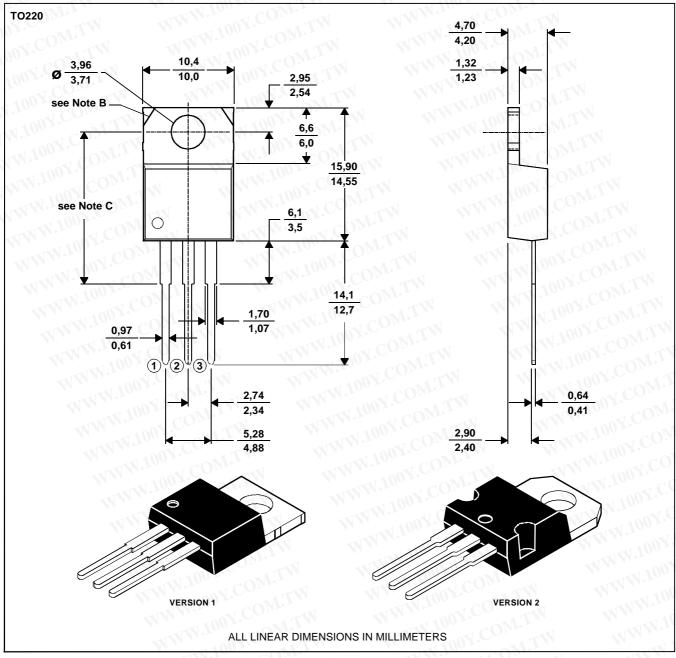
MMM.Tor

## **MECHANICAL DATA**

## **TO-220**

## 3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTES: A. The centre pin is in electrical contact with the mounting tab.

- B. Mounting tab corner profile according to package version.
- C. Typical fixing hole centre stand off height according to package version. Version 1, 18.0 mm. Version 2, 17.6 mm.

**MDXXBE** 

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